

EV3415

$R_{DS(on)} < 46 \text{ m}\Omega$ for $V_{GS} = -1.8 \text{ V}$, $I_D = -6 \text{ A}$
 $V_{GS(th)} < -1 \text{ V}$ for $V_{DS} = V_{GS}$, $I_D = -250 \mu\text{A}$
 $V_{DS} = -1 \text{ V}$ (body diode forward voltage)

SI2333

$R_{DS(on)} < 45 \text{ m}\Omega$ for $V_{GS} = -1.8 \text{ V}$, $I_D = -5 \text{ A}$
 $V_{GS(th)} < -1 \text{ V}$ for $V_{DS} = V_{GS}$, $I_D = -250 \mu\text{A}$
 $V_{DS} = -1.2 \text{ V}$ (body diode forward voltage)

